

# CD54HC4024, CD74HC4024, CD54HCT4024

Data sheet acquired from Harris Semiconductor SCHS202C

November 1997 - Revised October 2003

## High-Speed CMOS Logic 7-Stage Binary Ripple Counter

#### Features

- · Fully Static Operation
- Buffered Inputs
- Common Reset
- Negative Edge Clocking
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range . . . -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 30%, N<sub>IH</sub> = 30% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility,  $V_{IL}$ = 0.8V (Max),  $V_{IH}$  = 2V (Min)
  - CMOS Input Compatibility,  $I_I \le 1\mu A$  at  $V_{OL}$ ,  $V_{OH}$

#### Description

The 'HC4024 and 'HCT4024 are 7-stage ripple-carry binary counters. All counter stages are master-slave flip-flops. The state of the stage advances one count on the negative transition of each input pulse; a high voltage level on the MR line resets all counters to their zero state. All inputs and outputs are buffered.

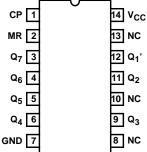
#### **Ordering Information**

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4024F3A	-55 to 125	14 Ld CERDIP
CD54HCT4024F3A	-55 to 125	14 Ld CERDIP
CD74HC4024E	-55 to 125	14 Ld PDIP
CD74HC4024M	-55 to 125	14 Ld SOIC
CD74HC4024MT	-55 to 125	14 Ld SOIC
CD74HC4024M96	-55 to 125	14 Ld SOIC
CD74HC4024PW	-55 to 125	14 Ld TSSOP
CD74HC4024PWR	-55 to 125	14 Ld TSSOP
CD74HC4024PWT	-55 to 125	14 Ld TSSOP
CD74HCT4024E	-55 to 125	14 Ld PDIP
CD74HCT4024M	-55 to 125	14 Ld SOIC

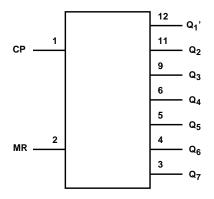
NOTE: When ordering, use the entire part number. The suffixes 96 and R denote tape and reel. The suffix T denotes a small-quantity reel of 250.

#### **Pinout**

CD54HC4024, CD54HCT4024 (CERDIP) CD74HC4024 (PDIP, SOIC, TSSOP) CD74HCT4024 (PDIP, SOIC) TOP VIEW



## Functional Diagram

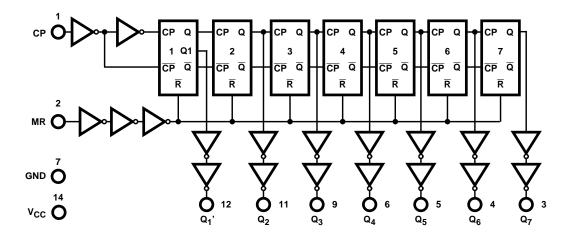


#### **TRUTH TABLE**

CP COUNT	MR	OUTPUT STATE
1	L	No Change
<b>\</b>	L	Advance to Next State
Х	Н	All Outputs Are Low

H = High Voltage Level, L = Low Voltage Level, X = Don't Care,

## Logic Diagram



 $<sup>\</sup>uparrow$  = Transition from Low to High Level,  $\downarrow$  = Transition from High to Low.

#### 

#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	$\theta_{JA}$ (°C/W)
E (PDIP) Package	80
M (SOIC) Package	86
PW (TSSOP) Package	113
(Maximum Junction Temperature	
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

#### **Operating Conditions**

Temperature Range (T <sub>A</sub> )55°C to 125°C
Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

#### **DC Electrical Specifications**

		TES CONDI		V <sub>CC</sub>	25°C			-40°C TO 85°C		-55°C TO 125°C														
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS												
HC TYPES																								
High Level Input	V <sub>IH</sub>	-	-	2	1.5	-	-	1.5	-	1.5	-	V												
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V												
				6	4.2	-	-	4.2	-	4.2	-	V												
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V												
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V												
				6	-	-	1.8	-	1.8	-	1.8	V												
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	V												
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V												
omeo Loudo			-0.02	6	5.9	-	-	5.9	-	5.9	-	V												
High Level Output	7		-	-	-	-	-	-	-	-	-	V												
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V												
112 20000			-5.2	6	5.48	-	-	5.34	-	5.2	-	V												
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	V												
Voltage CMOS Loads															0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWIGO Educa															Ī		0.02	6	-	-	0.1	-	0.1	-
Low Level Output	7							-	-	-	-	-	-	-	-	-	V							
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V												
TTE Education			5.2	6	-	-	0.26	-	0.33	-	0.4	V												
Input Leakage Current	lį	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ												
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	-	8	-	80	-	160	μΑ												

## DC Electrical Specifications (Continued)

		TE: CONDI	_	Vcc		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES	-		-		-	-	-	-	-			
High Level Input Voltage	V <sub>IH</sub>	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V <sub>IL</sub>	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	Voн	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lį	V <sub>CC</sub> and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI <sub>CC</sub> (Note 2)	V <sub>CC</sub> -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

#### NOTE:

#### **HCT Input Loading Table**

INPUT	UNIT LOADS
CP, MR	0.5

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Table, e.g., 360µA max at 25°C.

## **Prerequisite for Switching Specifications**

			25	o <sub>C</sub>	-40°C 1	TO 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-			-					-
Maximum Input Pulse	f <sub>MAX</sub>	2	6	-	5	-	4	-	MHz
Frequency		4.5	30	-	24	-	20	-	MHz
		6	35	-	29	-	24	-	MHz
Input Pulse Width	t <sub>W</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
Reset Removal Time	t <sub>REM</sub>	2	50	-	65	-	75	-	ns
		4.5	10	-	13	-	15	-	ns
		6	9	-	11	-	13	-	ns

<sup>2.</sup> For dual-supply systems theoretical worst case ( $V_I$  = 2.4V,  $V_{CC}$  = 5.5V) specification is 1.8mA.

## Prerequisite for Switching Specifications (Continued)

			25°C		-40°C T	O 85°C	-55°C T					
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS			
Reset Pulse Width	t <sub>W</sub>	2	80	-	100	-	120	-	ns			
		4.5	16	-	20	-	24	-	ns			
		6	14	-	17	-	20	-	ns			
HCT TYPES	ICT TYPES											
Maximum Input Pulse Frequency	f <sub>MAX</sub>	4.5	25	-	20	-	16	-	MHz			
Input Pulse Width	t <sub>W</sub>	4.5	20	-	25	=	30	-	ns			
Reset Recovery Time	t <sub>REC</sub>	4.5	10	-	13	-	15	-	ns			
Reset Pulse Width	t <sub>W</sub>	4.5	20	-	25	-	30	-	ns			

## Switching Specifications Input $t_{r}$ , $t_{f} = 6 \text{ns}$

		TEST	V <sub>CC</sub>		25°C		-40°C	ГО 85 <sup>0</sup> С	-55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay Time (Figure 1)	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	2	-	-	140	-	175	-	210	ns
CP to Q1' Output			4.5	-	-	28	-	35	-	42	ns
		C <sub>L</sub> =15pF	5	-	11	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	24	-	30	-	36	ns
Q <sub>n</sub> to Q <sub>n</sub> + 1	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
	t <sub>PHL</sub>		4.5	-	-	15	-	19	-	22	ns
		C <sub>L</sub> =15pF	5	-	6	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	13	-	13	-	19	ns
MR to Q <sub>n</sub>	t <sub>PLH</sub> ,	C <sub>L</sub> = 50pF	2	-	-	170	-	215	-	255	ns
	t <sub>PHL</sub>		4.5	-	-	34	-	43	-	51	ns
			5	-	14	-	-	-	-	-	ns
			6	-	-	29	-	27	-	43	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> =15pF	5	-	30	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay Time (Figure 2)	t <sub>PLH,</sub> t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	40	-	50	-	60	ns
CP to Q1' Output		C <sub>L</sub> =15pF	5	-	17	-	-	-	-	-	ns
Q <sub>n</sub> to Q <sub>n</sub> + 1	t <sub>PLH</sub> ,	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
	<sup>t</sup> PHL	C <sub>L</sub> =15pF	5	-	6	-	-	-	-	-	ns
MR to Q <sub>n</sub>	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	4.5	-	-	40	-	50	-	60	ns
	t <sub>PHL</sub>	C <sub>L</sub> =15pF	5	-	17	-	-	-	-	-	ns

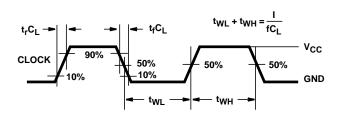
#### Switching Specifications Input $t_r$ , $t_f = 6ns$ (Continued)

		TEST	V <sub>CC</sub>	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Transition	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> =15pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C <sub>PD</sub>	C <sub>L</sub> =15pF	5	1	30	-	-	-	-	-	pF

#### NOTES:

- 3. CPD is used to determine the dynamic power consumption, per package.
- 4.  $P_D = V_{CC}^2 f_i + \sum (C_L V_{CC}^2 f_i/M)$  where:  $M = 2^1, 2^2, 2^3, 2^4, 2^5, 2^6, 2^7 f_i = Input Frequency, <math>C_L = Output Load Capacitance, V_{CC} = Supply Voltage.$

#### Test Circuits and Waveforms



NOTE: Outputs should be switching from 10%  $V_{CC}$  to 90%  $V_{CC}$  in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

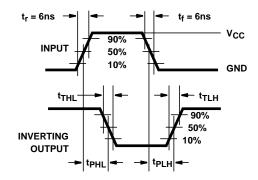
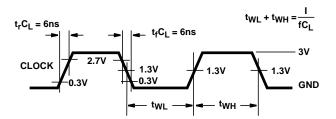


FIGURE 3. HC AND HCU TRANSITION TIMES AND PROPAGA-TION DELAY TIMES, COMBINATION LOGIC



NOTE: Outputs should be switching from 10%  $V_{CC}$  to 90%  $V_{CC}$  in accordance with device truth table. For  $f_{MAX}$ , input duty cycle = 50%.

FIGURE 2. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

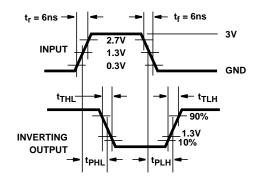


FIGURE 4. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

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#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD54HC4024F	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC4024F	Samples
CD54HCT4024F3A	ACTIVE	CDIP	J	14	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HCT4024F3A	Samples
CD74HC4024E	ACTIVE	PDIP	N	14	25	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4024E	Samples
CD74HC4024M	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4024M	Samples
CD74HC4024M96	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4024M	Samples
CD74HC4024MG4	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4024M	Samples
CD74HC4024MT	ACTIVE	SOIC	D	14	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4024M	Samples
CD74HC4024PW	ACTIVE	TSSOP	PW	14	90	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4024	Samples
CD74HC4024PWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4024	Samples
CD74HCT4024E	ACTIVE	PDIP	N	14	25	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4024E	Samples
CD74HCT4024EE4	ACTIVE	PDIP	N	14	25	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4024E	Samples
CD74HCT4024M	ACTIVE	SOIC	D	14	50	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4024M	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet J\$709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

#### PACKAGE OPTION ADDENDUM

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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD54HC4024, CD54HCT4024, CD74HC4024, CD74HCT4024:

Catalog: CD74HC4024, CD74HCT4024

Military: CD54HC4024, CD54HCT4024

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

## PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4024M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC4024MT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HC4024PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

**PACKAGE MATERIALS INFORMATION** 

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\*All dimensions are nominal

, in difference are normal								
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD74HC4024M96	SOIC	D	14	2500	853.0	449.0	35.0	
CD74HC4024MT	SOIC	D	14	250	210.0	185.0	35.0	
CD74HC4024PWR	TSSOP	PW	14	2000	853.0	449.0	35.0	

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
  Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
  Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



## D (R-PDSO-G14)

#### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



## D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

#### PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



## PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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